Philosophical Magazine

First Published in 1798

Physics of Condensed Matter

A Defects and Mechanical Properties

B Structural, Electronic, Optical and Magnetic Properties

Recognized by the European Physical Society

Taylor & Francis
London • Washington, DC

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Subscription Information

Philosophical Magazine A (ISSN 0141-8610) is published monthly by Taylor & Francis Ltd, 4 John Street, London WC1N 2ET, UK.

Annual Subscription 1991 £650 US$1125.

Second class postage paid at Jamaica, New York 11431. USA Postmasters: Send address changes to *Philosophical Magazine*, Publications Expediting Inc., 200 Meachan Avenue, Elmont, New York 11003. Air freight and mailing in the USA by Publications Expediting Inc., 200 Meacham Avenue, Elmont, New York 11003.

Printed in UK by Burgess Science Press, Rankine Road, Basingstoke, Hampshire RG24 0PR, UK. The paper used in this publication has a specified pH value on final manufacture of not less than 7·5 and is therefore 'acid free'.

Subscription prices includes parts A and B and Letters, none of which is available separately. Dollar rates apply to subscribers in all countries except the UK and the Republic of Ireland where the pound sterling price applies. All subscriptions are payable in advance and all rates include postage. Journals are sent by air to the USA, Canada, Mexico, India, Japan and Australasia. Subscriptions are entered on an annual basis, i.e. January to December. Payment may be made by sterling cheque, dollar cheque, international money order, National Giro, or credit card (Amex, Visa, Mastercard/Access).

Orders originating in the following territories should be sent direct to the local distributor. **Australia:** R. Hill & Son Ltd, Suite 2, 119 Gardenvale Road, Gardenvale, Victoria, 3185. **New Zealand:** R. Hill & Son Ltd, Private Bag, Newmarket, Auckland 1. **India:** Universal Subscription Agency Pvt. Ltd, 101–102 Community Centre, Malviya Nagar Extn, Post Bag No. 8, Saket, New Delhi 110017. **Japan:** Kinokuniya Company Ltd, Journal Department, PO Box 55, Chitose, Tokyo 156. **USA, Canada and Mexico:** Taylor & Francis, Inc., 1900 Frost Road, Suite 101, Bristol, Pennsylvania 19007. **UK and all other territories:** Taylor & Francis Ltd, Rankine Road, Basingstoke, Hampshire RG24 0PR.

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